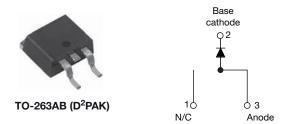
RoHS



Vishay Semiconductors

High Performance Schottky Rectifier, 20 A

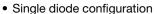


PRODUCT SUMMARY							
Package	TO-263AB (D ² PAK)						
I _{F(AV)}	20 A						
V _R	15 V						
V _F at I _F	0.33 V						
I _{RM} max.	600 mA at 100 °C						
T _J max.	125 °C						
E _{AS}	10 mJ						
Diode variation	Single die						

FEATURES

High



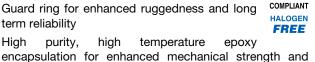


moisture resistance



Ultralow forward voltage drop

 Guard ring for enhanced ruggedness and long term reliability



• Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

Designed and qualified according to JEDEC®-JESD47

· Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	А						
V _{RRM}		15	V						
I _{FSM}	$t_p = 5 \mu s \text{ sine}$	700	Α						
V _F	19 A _{pk} , T _J = 125 °C (typical)	0.25	V						
TJ	Range	-55 to +125	°C						

VOLTAGE RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VS-20L15TS-M3	UNITS			
Maximum DC reverse voltage	V_R	T _{.1} = 100 °C	15	V			
Maximum working peak reverse voltage	V_{RWM}	1j = 100 C	15	V			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 85 °C, rec	20					
Maximum peak one cycle non-repetitive	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	700	Α			
surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	330				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 6 \text{mH}$		10	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	А			



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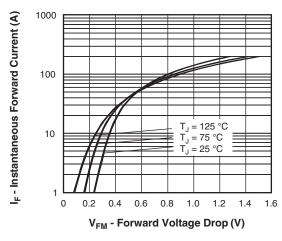
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TYP.	MAX.	UNITS			
		19 A	T _{.1} = 25 °C	-	0.41	V		
Forward voltage drop	V _{FM} ⁽¹⁾	40 A	1j=25 C	-	0.52			
See fig. 1	VFM (1)	19 A	T _J = 125 °C	0.25	0.33			
		40 A	1J=125 C	0.37	0.50			
Reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	-	10	- mA		
See fig. 2		T _J = 100 °C	v _R = nateu v _R	-	600			
Threshold voltage	V _{F(TO)}	$T_{.1} = T_{.1}$ maximum		0.182		V		
Forward slope resistance	r _t	rj = rj maximum	7.6		mΩ			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} , (test signal ran	-	2000	pF			
Typical series inductance	L _S	Measured lead to lead 5 m	8	-	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs			

Note

 $^{(1)}\,$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction temperature range	TJ		-55 to +125	°C				
Maximum storage temperature range	T _{Stg}		-55 to +150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (For TO-220)	0.50	°C/W				
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation	40					
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting targue		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque maximum		Non-iudricated threads	12 (10)	(lbf · in)				
Marking device		Case style D ² PAK	20L15TS					





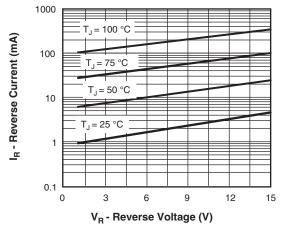


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

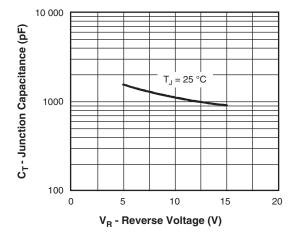


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

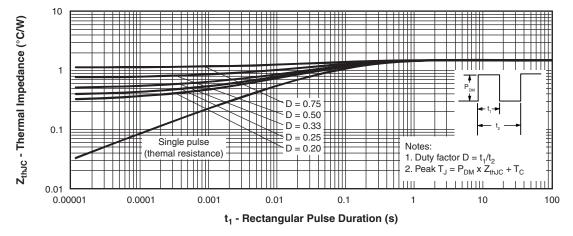


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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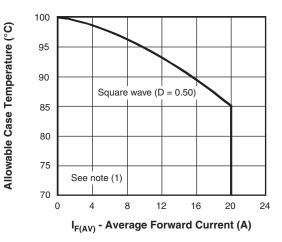


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

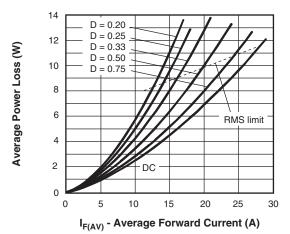


Fig. 6 - Forward Power Loss Characteristics

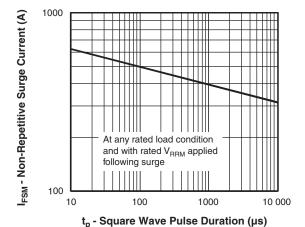


Fig. 7 - Maximum Non-Repetitive Surge Current

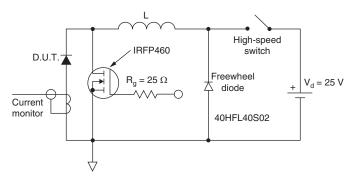


Fig. 8 - Unclamped Inductive Test Circuit

Note

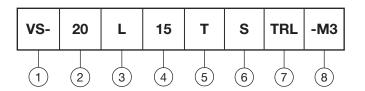
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (20 A)

3 - L = Low V_F

Voltage rating (15 = 15 V)

5 - T = Schottky series

7 - • None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - -M3 = halogen-free, RoHS-compliant and termination lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-20L15TS-M3	50	1000	Antistatic plastic tubes						
VS-20L15TSTRL-M3	800	800	13" diameter reel						
VS-20L15TSTRR-M3	800	800	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046					
Part marking information	TO-263AB (D ² PAK)	www.vishay.com/doc?95444					
Packaging information		www.vishay.com/doc?95032					



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	HES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3	
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3	
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3	
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625		
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110		
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3	
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070		
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC		
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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Vishay

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